NSN 5961-01-220-8117

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View Online at https://aerobasegroup.com/nsn/5961-01-220-8117 **Inclosure Material:** Ceramic **Overall Length:** 0.620 inches **End Application:** Aircraft model sh-60b **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected **Mounting Method:** Unthreaded hole **Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 80.0 collector to emitter voltage/static/base open and 80.0 collector to base voltage, dc and 5.0 emitter to base voltage, dc **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector megawatts **Transfer Ratio:** 4.0 small-signal short-circuit forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 120.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: A110a0